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Fundamental Radiometry and Photometry

Introduction

The responsivity of ON Semiconductor image sensors is measured and specified in radiometric units, which have meaning throughout the entire electro-magnetic spectrum. Radiometric units are purely physical quantities in contrast to photometric quantities that are based on the response of the human eye. Thus, photometry is the measurement of the ability of electromagnetic radiation to induce a visual sensation in a physically realizable manner, that is, via a defined simulation of human vision, the CIE (Commission Internationale de l'Éclairage) standard observer.

In this application note, we provide some of the basic concepts and definitions of radiometry and photometry and show how one can convert from one set of units to the other.

Basic Definitions and Concepts

In the following discussion, only basic concepts and definitions of radiometry and photometry are discussed. More detailed discussions can be found in the references listed in the bibliography at the end of this note.

A source emits a radiant flux (φ_e) that is proportional to the area enclosed by its spectral distribution curve:

$$\varphi_e = \int_0^\infty \varphi_{e,\lambda} d\lambda \quad (W) \quad (\text{eq. 1})$$

Radiance is the radiant flux per unit area and unit solid angle arriving at or leaving from a surface from a given point:

$$L_e = \frac{d\varphi_e}{dA \cos \theta d\Omega} \left(\frac{W}{m^2 \text{sr}} \right) \quad (\text{eq. 2})$$

Now, to determine the capacity of the radiant flux to create the sensation of light, the $\varphi_{e,\lambda}$ curve must be transformed to a luminous flux.

This is accomplished by multiplying φ_e by the photopic relative luminous efficiency function $V(\lambda)$.

$$\varphi_v = \int_{380}^{780} \varphi_{e,\lambda} V(\lambda) d\lambda \quad (W) \quad (\text{eq. 3})$$

$V(\lambda)$ is the ratio of the radiant flux at wavelength λ_m to that at wavelength λ , when the two fluxes produce the same photopic luminous sensation under specified photometric conditions. λ_m is chosen so that the maximum value of this ratio is unity. In essence, $V(\lambda)$ is the spectral response of the human eye normalized so that it has the value 1 at 555 nm, the peak of the human eye's response.

Table 1 lists the values of $V(\lambda)$ and Figure 1 shows the response graphically.

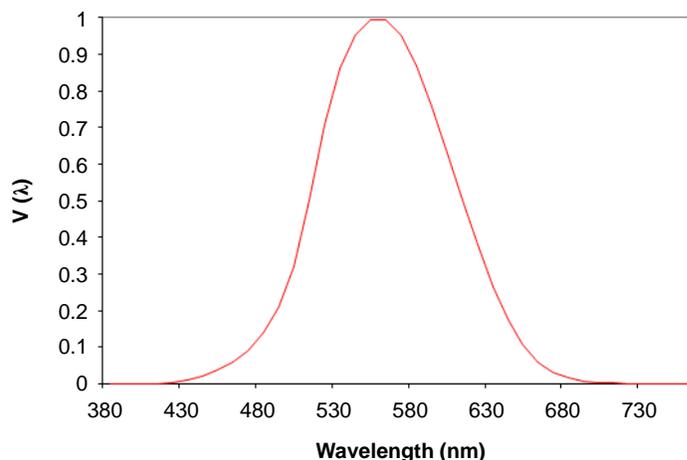


Figure 1. Photopic Response of the Human Eye (CIE Standard Observer)

Table 1. PHOTOPIC RELATIVE LUMINOUS EFFICIENCY FUNCTION V(λ) AND LUMINOUS EFFICACY OF THE STANDARD OBSERVER

λ (nm)	V (λ)	K (λ)	λ (nm)	V (λ)	K (λ)
380	0	0	580	0.87	594.21
390	0.0001	0.0683	590	0.757	517.031
400	0.0004	0.2732	600	0.631	430.973
410	0.0012	0.8196	610	0.503	343.549
420	0.004	2.732	620	0.381	260.223
430	0.0116	7.9228	630	0.265	180.995
440	0.023	15.709	640	0.175	119.525
450	0.038	25.954	650	0.107	3.081
460	0.06	40.98	660	0.061	41.663
470	0.091	62.153	670	0.032	21.856
480	0.139	94.937	680	0.017	11.611
490	0.208	142.064	690	0.0082	5.6006
500	0.323	220.609	700	0.0041	2.8003
510	0.503	343.549	710	0.0021	1.4343
520	0.71	484.93	720	0.001	0.683
530	0.862	588.746	730	0.0005	0.3415
540	0.954	651.582	740	0.0003	0.2049
550	0.995	679.585	750	0.0001	0.0683
560	0.995	679.585	760	0.0001	0.0683
570	0.952	650.216	770	0	0

Since V(λ) is dimensionless, φ_V remains in units of watts, although the units might be better thought of as lightwatts as we are now in the visual domain.

To convert the luminous flux from watts (lightwatts) to the photometric equivalent, lumens, multiply Equation 3 by the maximum luminous efficacy factor, K_m:

$$\varphi_V = K_m \int_{380}^{780} \varphi_{e,\lambda} V(\lambda) d\lambda \quad (\text{lumens}) \quad (\text{eq. 4})$$

For photopic vision the maximum luminous efficacy of radiant flux (K_m) is 683 lumens watt⁻¹.

Luminance is the photometric unit corresponding to radiance and is defined in the same way:

$$L_V = \frac{d\varphi_V}{dA \cos \theta d\Omega} \quad (\text{eq. 5})$$

The luminous efficacy of the total radiant flux is represented by the symbol K and is the product of the luminous efficiency V and the maximum luminous efficacy factor K_m

$$K = V \cdot K_m = \frac{\varphi_V}{\varphi_e} \quad (\text{eq. 6})$$

When luminous flux is expressed in lumens and not watts, then V(λ) becomes spectral luminous efficacy of radiant flux K(λ). It is expressed in lumens watt⁻¹:

$$K(\lambda) = V(\lambda) \cdot K_m \quad (\text{eq. 7})$$

From the foregoing, then, knowing the radiant flux incident on the detector, it is possible to convert to a luminous flux, which is the desired quantity.

A table of radiometric and photometric terms and units showing their relationships is provided in Appendix I.

Conversion from Radiometric to Photometric Units

Conversion of the radiometric responsivity (R_e) of a sensor to photometric responsivity (R_V) first requires knowledge of the light source. If the source is specified as having a certain color temperature, and we assume that its exitance is the same as a perfect blackbody radiator, then its spectral radiance, in W·cm⁻² nm⁻¹ sr⁻¹ is given by Planck's Law.

$$L_{e\lambda} = \frac{3.741 \times 10^{19}}{\pi \lambda^5 \left[e^{\left(\frac{14388000}{\lambda T} \right)} - 1 \right]} \quad (\text{eq. 8})$$

where λ is in nm and T is in Kelvin.

Artificial sources, in general, do not have the same spectral distribution as a perfect blackbody but, for our purposes, we shall consider them equal. Figure 2 depicts spectral radiance of several blackbody radiators.

Sensor responsivity is derived from the relationship between the number and energy of photons arriving at the sensor, the ability of the sensor to convert them into electrons and ultimately into an output voltage. For an incident beam with radiant flux ϕ_λ and photons with energy $E = h\nu$, the number of photons arriving at the detector is $\phi_\lambda/h\nu$. The detector converts photons to electrons with quantum efficiency ξ , so the number of electrons produced per unit time is $N_e = \xi\phi_\lambda/h\nu$.

If each electron contributes to the output signal, then the voltage is $N_e \cdot O$, where O is the product of charge-to-voltage conversion and the internal sensor gain. It is measured in units of volts/e⁻. The voltage then is $V_\lambda = (\xi O/h\nu) \phi_\lambda$. Spectral responsivity is

$$R(\lambda) = \frac{V_\lambda}{\phi_\lambda} = \frac{\xi O}{h\nu} \quad (\text{eq. 9})$$

Integrating over the wavelength range that the sensor is sensitive yields the total responsivity.

$$R = \frac{\int_\lambda V_\lambda d\lambda}{\int_\lambda \phi_\lambda d\lambda} \quad (\text{eq. 10})$$

The output of the sensor, ignoring integration time, becomes

$$V_{\text{out}} = L_e \cdot R \quad (\text{eq. 11})$$

The same analysis applies for responsivity in terms of luminous flux. Consequently, we can arrive at an expression for the photometric responsivity, R_v as a function of the radiometric responsivity, R_e :

$$R_v = \frac{\int_\lambda L_{e\lambda} R_{e\lambda} d\lambda}{K_m \int_\lambda L_{e\lambda} V(\lambda) d\lambda} \cdot \lambda \quad (\text{eq. 12})$$

This is best shown by example.

Example

A KLI-8013 Image Sensor with the standard CFA is used in an imaging application that uses a 3200K halogen light source and a BG-38 IR cutoff filter glass 2 mm thick. The blue channel radiometric responsivity is listed in column 2 of Table 2 in units of $V \mu J^{-1} \text{ cm}^{-2}$. What is the photometric responsivity of the blue channel in $V (\text{lux sec})^{-1}$?

For simplicity, and since this is a relative comparison, we ignore integration time and the effects caused by any optical elements in the imaging system.

First we must calculate the spectral radiance of the lamp or obtain the information from actual measurements (or manufacturer’s data). Calculated radiance (Equation 8) for a 3200K source is shown in column 3 of Table 2.

The actual radiance incident on the sensor is shaped by the effect of the BG-38 filter glass.

$$L_{e\lambda \text{ net}} = L_{e\lambda} \cdot \tau_{\text{BG-38}} \quad (\text{eq. 13})$$

where, $\tau_{\text{BG-38}}$ is the transmittance through the filter glass (column 4).

For practical purposes, we can replace the integration over the visible spectrum of infinitely small strips of wavelength width $d\lambda$ with the summation of strips of finite width $\Delta\lambda$ (10 nm in this case). Thus, the rest of the calculation is straightforward and is detailed in columns 6 and 7.

The result is that the blue channel photometric response of this sensor and CFA, illuminated by a 3200K source is

$$R_v = \frac{100 \times 2.78 \times 10^4}{4.12 \times 10^6} = 0.675 \text{ V lux}^{-1} \text{ sec}^{-1} \quad (\text{eq. 14})$$

NOTE: Note: The additional factor of 100 is a result of converting μJ to watts and m^2 to cm^2 .

Similarly, the green channel response is $1.4 \text{ V lux}^{-1} \text{ sec}^{-1}$, and the red channel response is $3.45 \text{ V lux}^{-1} \text{ sec}^{-1}$.

This exercise shows that without full knowledge of all system parameters – optical system throughput, light source spectral radiance, filter glass transmission, and sensor responsivity – conversion from radiometric to photometric units is not possible.

Table 2. VALUES OF SPECTRAL RADIANCE AND FILTER GLASS TRANSMISSION USED TO CALCULATE LUMINOUS RESPONSIVITY FROM RADIOMETRIC RESPONSIVITY

Spectral Radiance						
Wavelength	Response $V \text{ mJ}^{-1} \text{ cm}^{-2}$	3200 K Source $W \text{ cm}^{-2} \text{ nm}^{-1} \text{ sr}^{-1}$	BG-38 Transmission	Net Radiance	$L_{e\lambda} * R_\lambda$	$L_{e\lambda} * V(\lambda)$
360	0.03	7.42E+00	0.798	5.92E+00	1.75E-01	0.00E+00
370	0.09	9.06E+00	0.834	7.56E+00	6.85E-01	0.00E+00
380	0.39	1.09E+01	0.861	9.40E+00	3.64E+00	0.00E+00
390	1.17	1.30E+01	0.87	1.13E+01	1.33E+01	1.13E-03
400	2.48	1.53E+01	0.877	1.34E+01	3.32E+01	5.36E-03
410	4.26	1.78E+01	0.882	1.57E+01	6.67E+01	1.88E-02
420	5.78	2.04E+01	0.886	1.81E+01	1.05E+02	7.24E-02
430	7.1	2.33E+01	0.891	2.08E+01	1.47E+02	2.41E-01

Table 2. VALUES OF SPECTRAL RADIANCE AND FILTER GLASS TRANSMISSION USED TO CALCULATE LUMINOUS RESPONSIVITY FROM RADIOMETRIC RESPONSIVITY (continued)

Wavelength	Response V mJ ⁻¹ cm ⁻²	3200 K Source W cm ⁻² nm ⁻¹ sr ⁻¹	BG-38 Transmission	Net Radiance	L _{eλ} * R _λ	L _{eλ} * V(λ)
440	8.29	2.63E+01	0.893	2.35E+01	1.95E+02	5.41E-01
450	9.18	2.95E+01	0.897	2.65E+01	2.43E+02	1.01E+00
460	9.41	3.29E+01	0.899	2.96E+01	2.78E+02	1.77E+00
...						
700	0.11	1.15E+02	0.224	2.58E+01	2.84E+00	1.06E-01
710	0.37	1.18E+02	0.187	2.20E+01	8.16E+00	4.61E-02
720	1.23	1.20E+02	0.155	1.85E+01	2.27E+01	1.85E-02
730	3.19	1.22E+02	0.128	1.56E+01	4.97E+01	7.79E-03
740	6.57	1.24E+02	0.106	1.31E+01	8.61E+01	3.93E-03
750	10.22	1.25E+02	0.087	1.09E+01	1.11E+02	1.09E-03
760	14.22	1.27E+02	0.072	9.14E+00	1.30E+02	9.14E-04

Notes:

1. $K_m \sum_{\lambda=360}^{760} L_{e\lambda} V(\lambda) \Delta\lambda = 4.12 \times 10^6$, where $K_m = 683 \frac{\text{lumens}}{\text{W}}$ from Equation 4.
2. $\sum_{\lambda=360}^{760} L_{e\lambda} R_{e\lambda} \Delta\lambda = 2.78 \times 10^4$.

Blackbody Radiance Curves

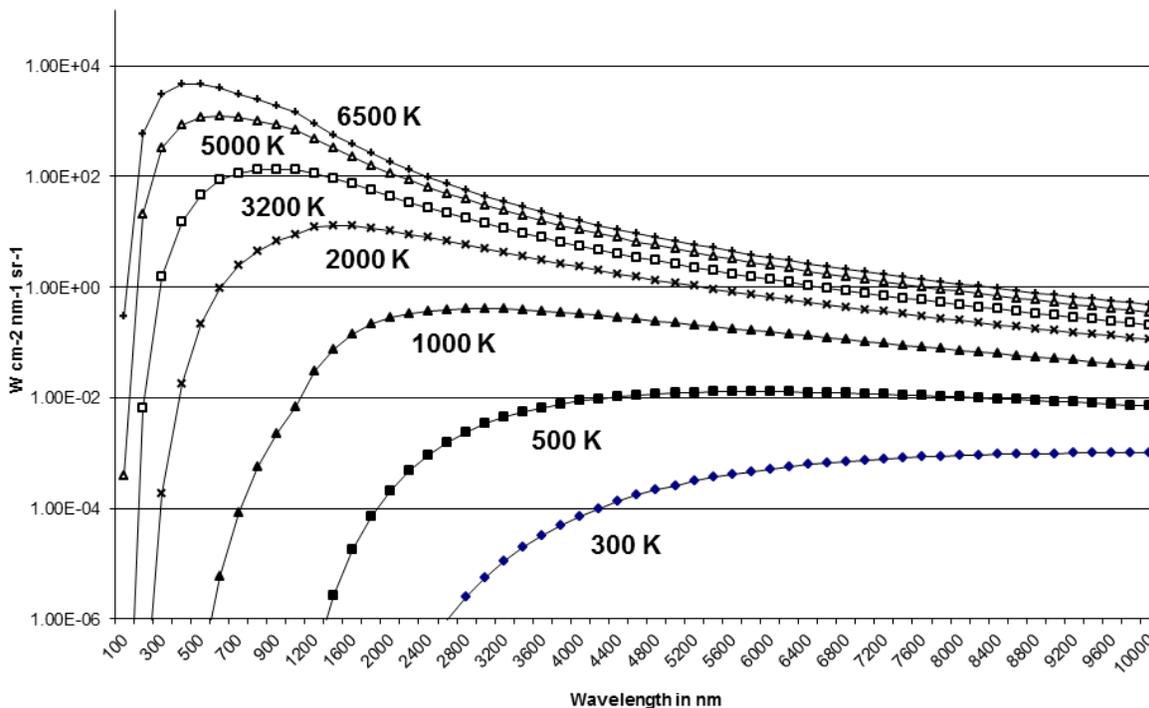


Figure 2. Blackbody Radiation Curves for Various Source Color Temperatures, Calculated from Planck's Law

APPENDIX I

Table 3. FUNDAMENTAL RADIOMETRIC AND PHOTOMETRIC QUANTITIES

Fundamental Radiometric Quantities			Fundamental Photometric Quantities		
Quantity	Symbol	Units	Quantity	Symbol	Units
Radiant Energy	Qe	J (joule)	Luminous Energy	Qv	lm s
Radiant Energy Density	we	J m ⁻³	Luminous Energy Density	Wv	lm s m ⁻³
Radiant Power or Flux	φe	W (watt)	Luminous Flux	φv	lm
Radiant Exitance	Me	W m ⁻²	Luminous Exitance	Mv	lm m ⁻²
Irradiance	Ee	W m ⁻²	Illuminance	Ev	lm m ⁻²
Radiant Intensity	Ie	W sr ⁻¹	Luminous Intensity	Iv	cd = lm sr ⁻¹
Radiance	Le	W m ⁻² sr ⁻¹	Luminance	Lv	cd m ⁻²
Emissivity	ε	-	Luminous Efficacy	K	lm W ⁻¹
			Photopic Luminous Efficiency	V(λ)	-
			Maximum Spectral luminous Efficacy	Km	lm W ⁻¹

NOTE: cd is candela; lm is lumen; sr is steradian

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